

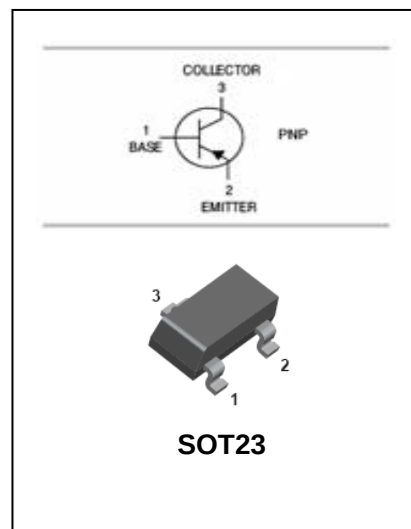
PNP General Purpose Transistor

FEATURES

- Epitaxial planar die construction.
- Complementary NPN type available (MMBT3904).
- Collector Current Capability $I_{CM} = -200\text{mA}$.
- Low Voltage(Max:-40V).



Lead-free



APPLICATIONS

- Ideal for medium power amplification and switching.

ORDERING INFORMATION

Type No.	Marking	Package Code
MMBT3906X	2A	SOT23

MAXIMUM RATING @ $T_a = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	Value	UNIT
V_{CBO}	collector-base voltage	open emitter	-40	V
V_{CEO}	collector-emitter voltage	open base	-40	V
V_{EBO}	emitter-base voltage	open collector	-5	V
I_C	collector current (DC)		-200	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25^\circ\text{C}$	200	mW
T_{stg}	storage temperature		-55 to +150	$^\circ\text{C}$
T_j	junction temperature		150	$^\circ\text{C}$

Note Transistor mounted on an FR4 printed-circuit board.

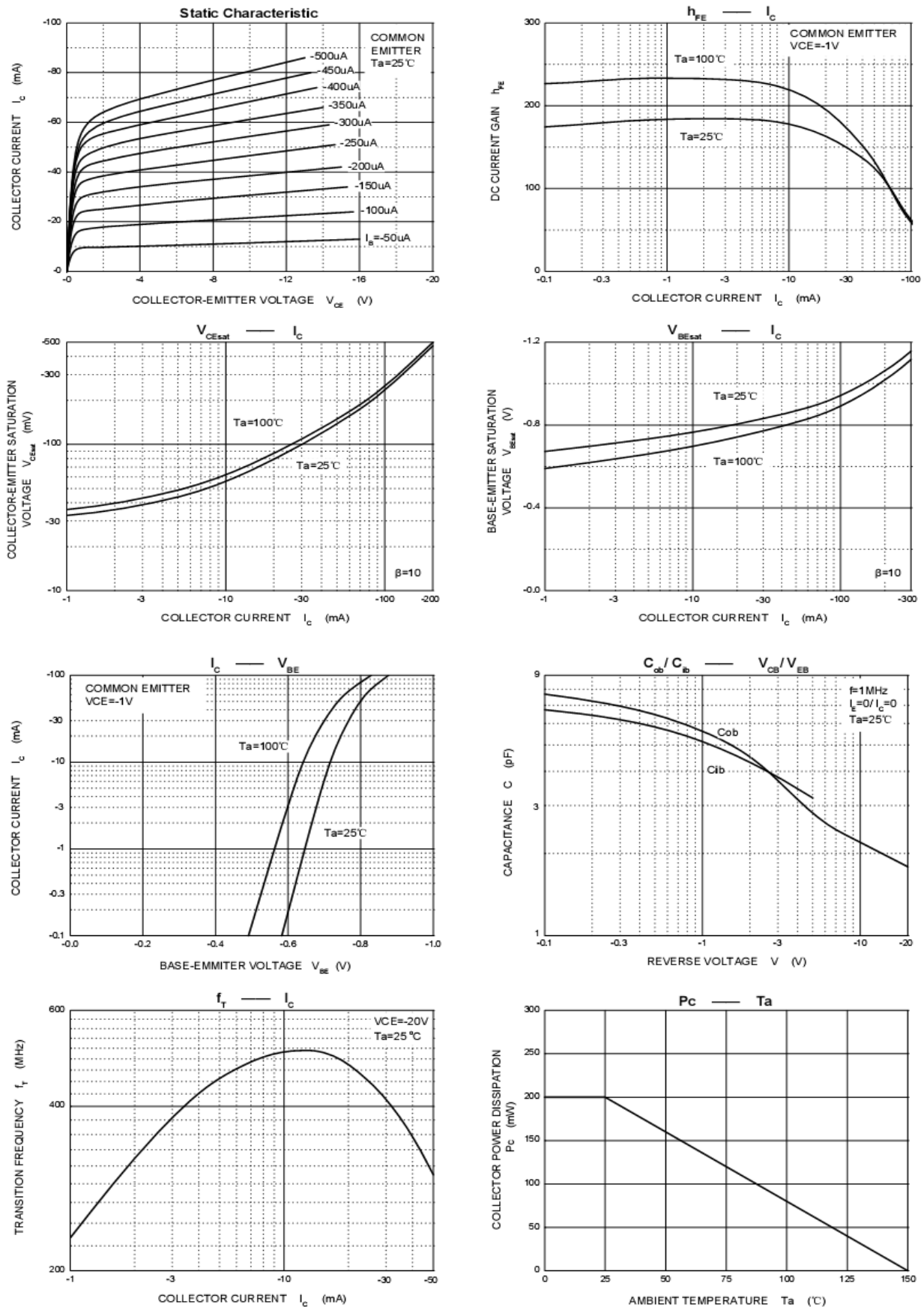
PNP General Purpose Transistor
ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_{CBO}	collector cut-off current	$I_E = 0; V_{CB} = -40\text{ V}$	-	-0.1	uA
I_{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = -5\text{ V}$	-	-0.1	uA
h_{FE}	DC current gain	$V_{CE} = -1\text{V};$ $I_C = -10\text{mA}$ $I_C = -50\text{mA}$ $I_C = -100\text{mA}$	100 60 30	- 300 -	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10\text{mA}; I_B = -1\text{mA}$	-	-200	mV
		$I_C = -50\text{mA}; I_B = -5\text{mA}$	-	-400	mV
V_{BEsat}	base-emitter saturation voltage	$I_C = -10\text{mA}; I_B = -1\text{mA}$	-	-850	mV
		$I_C = -50\text{mA}; I_B = -5\text{mA}$	-	-950	mV
f_T	transition frequency	$I_C = -10\text{mA}; V_{CE} = -20\text{ V};$ $f = 100\text{MHz}$	300	-	MHz
Switching times (between 10% and 90% levels);					
t_d	delay time	$V_{CC} = -3\text{V}; I_C = -10\text{mA};$ $I_{B1} = I_{B2} = -1\text{mA}$	-	35	ns
t_r	rise time		-	35	ns
t_s	storage time		-	225	ns
t_f	fall time		-	75	ns

Note Pulse test: $t_p \leq 300\text{ ms}; d \leq 0.02$.

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TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

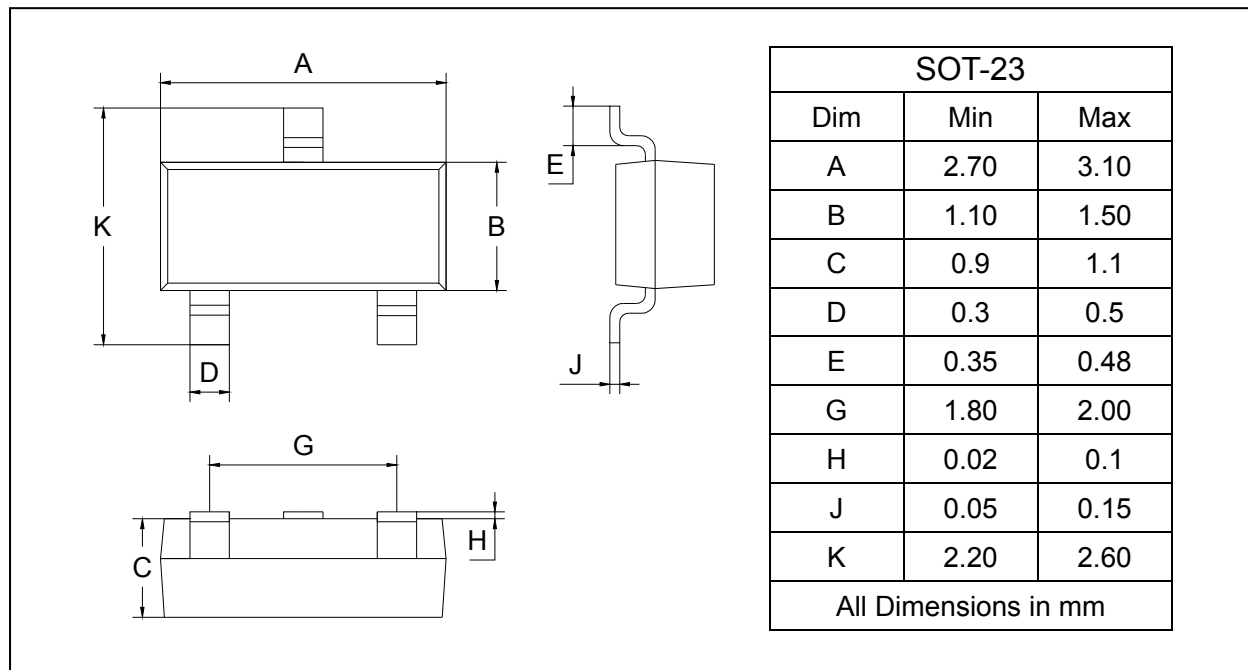


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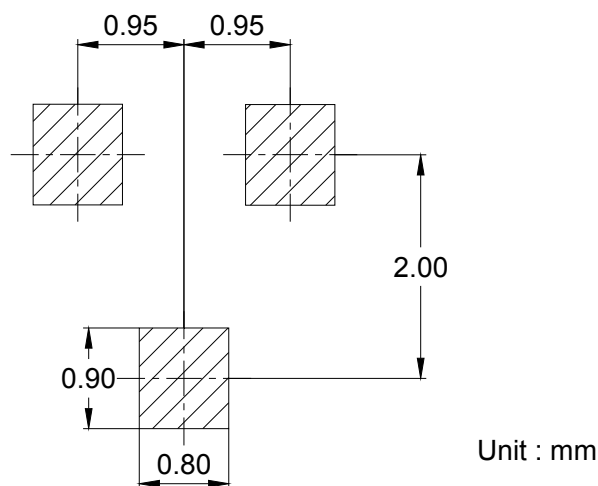
PACKAGE OUTLINE

Plastic surface mounted package

SOT23



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
MMBT3906X	SOT23	3000/Tape&Reel